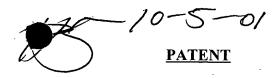
Docket No.: 43890-449



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of

Hidenori KAMEI, et al.

Serial No .:

Group Art Unit:

Filed: October 10, 2000

Examiner:

For:

P-TYPE NITRIDE SEMICONDUCTOR AND METHOD OF MANUFACTURING THE

SAME

INFORMATION DISCLOSURE STATEMENT

Assistant Commissioner for Patents Washington, DC 20231

Dear Sir:

In accordance with the provisions of 37 C.F.R. 1.56, 1.97 and 1.98, the attention of the Patent and Trademark Office is hereby directed to the documents listed on the attached form PTO-1449. It is respectfully requested that the documents be expressly considered during the prosecution of this application, and that the documents be made of record therein and appear among the "References Cited" on any patent to issue therefrom.

This Information Disclosure Statement is being filed within three months of the U.S. filing date OR before the mailing date of a first Office Action on the merits. No certification or fee is required.

Respectfully submitted,

MCDERMOTT, WILL & EMERY

Michael E. Fogarty
Registration No. 36,139

600 13th Street, N.W. Washington, DC 20005-3096 (202) 756-8000 MEF:dtb

Date: October 10, 2000 Facsimile: (202) 756-8087